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Front Matter: Volume 8980

, "Front Matter: Volume 8980," Proc. SPIE 8980, Physics and Simulation of Optoelectronic Devices XXII, 898001 (28 March 2014); doi: 10.1117/12.2063466

SPIE.

Event: SPIE OPTO, 2014, San Francisco, California, United States

PROCEEDINGS OF SPIE

Physics and Simulation of Optoelectronic Devices XXII

**Bernd Witzigmann
Marek Osiński
Fritz Henneberger
Yasuhiko Arakawa**
Editors

**3–6 February 2014
San Francisco, California, United States**

Sponsored and Published by
SPIE

Volume 8980

Proceedings of SPIE 0277-786X, V. 8980

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

Physics and Simulation of Optoelectronic Devices XXII, edited by Bernd Witzigmann, Marek Osinski,
Fritz Henneberger, Yasuhiko Arakawa, Proc. of SPIE Vol. 8980, 898001 · © 2014 SPIE
CCC code: 0277-786X/14/\$18 · doi: 10.1117/12.2063466

Proc. of SPIE Vol. 8980 898001-1

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Author(s), "Title of Paper," in *Physics and Simulation of Optoelectronic Devices XXII*, edited by Bernd Witzigmann, Marek Osinski, Fritz Henneberger, Yasuhiko Arakawa, Proceedings of SPIE Vol. 8980 (SPIE, Bellingham, WA, 2014) Article CID Number.

ISSN: 0277-786X

ISBN: 9780819498939

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445

SPIE.org

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Printed in the United States of America.

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